

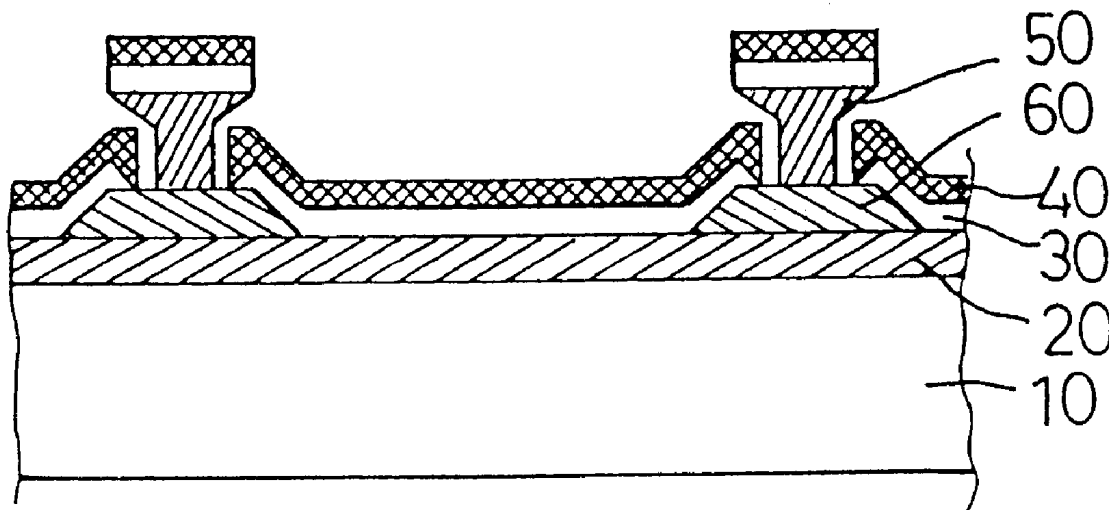
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|-----------|------------------------------|-----------|---------------------|---------|
| (56) | References Cited | | | |
| | U.S. PATENT DOCUMENTS | | | |
| 5,701,055 | A | 12/1997 | Nagyama et al. | 313/504 |
| 5,962,970 | A | * 10/1999 | Yokio et al. | |
| 6,013,538 | A | * 1/2000 | Burrows et al. | |
| 6,140,765 | A | 10/2000 | Kim et al. | 313/506 |

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A surface treatment process for fabricating a panel of an organic light emitting device is disclosed. The surface treatment process for fabricating a panel of an organic light emitting device comprises following steps: forming on a substrate a plurality of first electrodes; forming a plurality of ramparts having T-shape cross-section on said substrate and selectively on said first electrodes through coating positive chemically amplified photoresist compositions having photo-acid generators on said substrate, exposing coated substrate to UV radiation to form latent pattern, post-exposure surface treating said photoresist on said substrate in a alkaline atmosphere and developing said photoresist; wherein each rampart protruding from said substrate and having an overhanging portion projecting in a direction parallel to said substrate; depositing organic electroluminescent media to the exposed area between said ramparts on said substrate; forming a plurality of second electrodes on said organic electroluminescent media on said substrate.

19 Claims, 2 Drawing Sheets



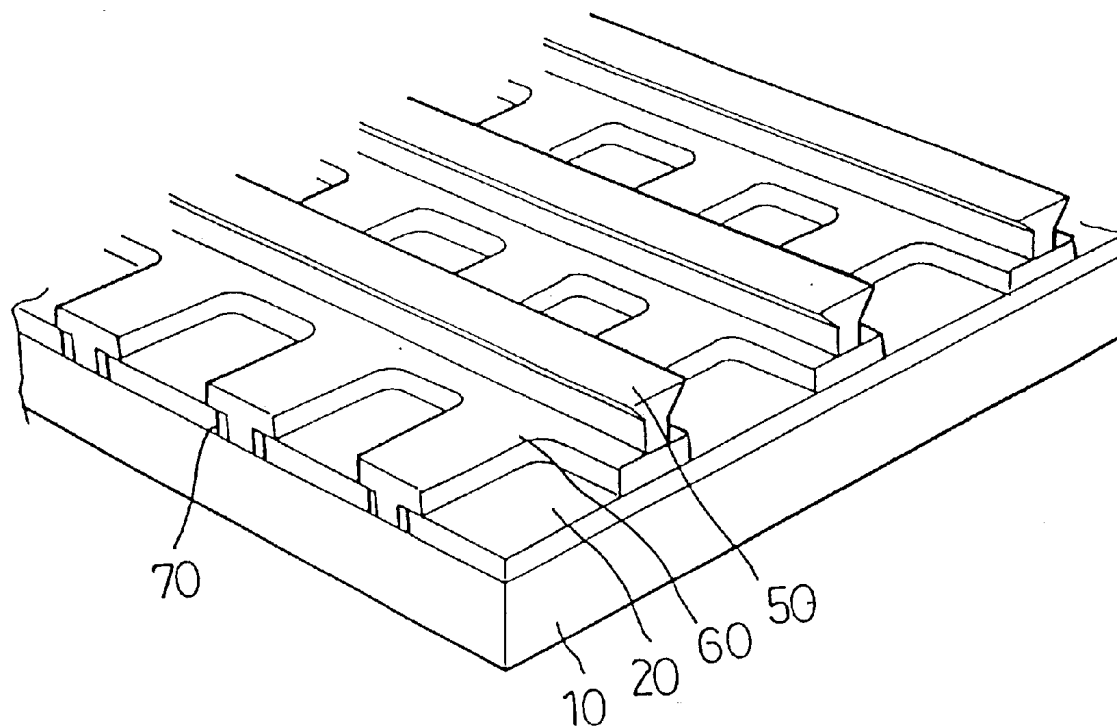


Fig. 1

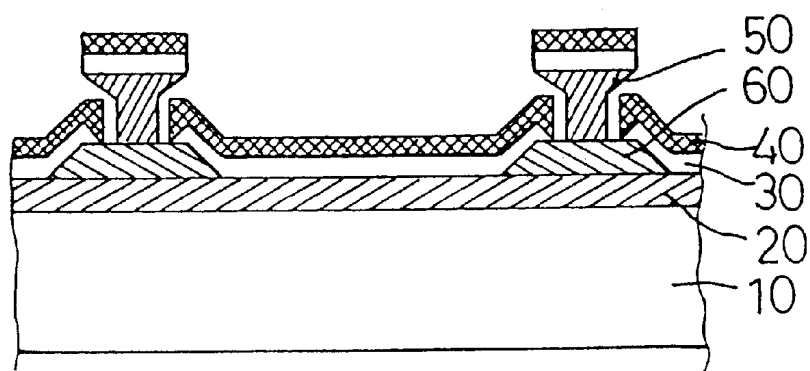


Fig. 2

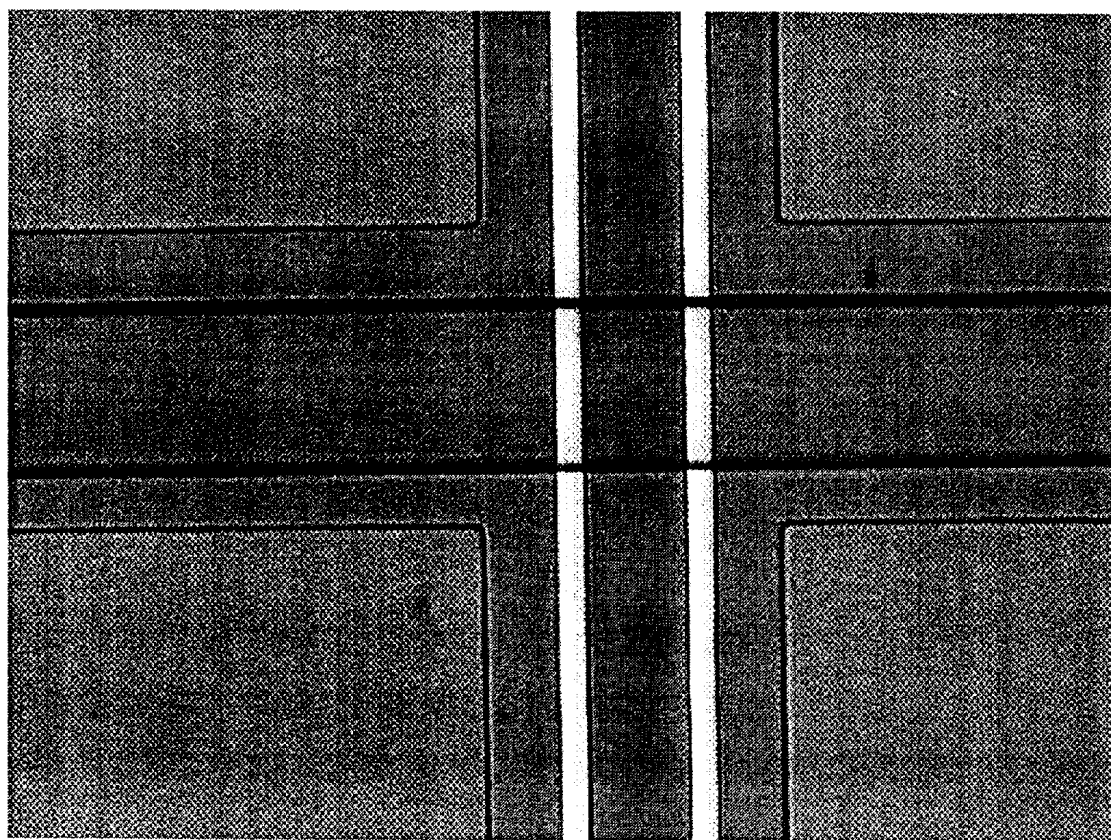


Fig. 3

SURFACE TREATMENT PROCESS FOR FABRICATING A PANEL OF AN ORGANIC LIGHT EMITTING DEVICE

FIELD OF THE INVENTION

The present invention relates to a surface treatment process for fabricating a panel of an organic light emitting device (OLED), especially associates to a surface treatment process for the isolating walls on a panel of an OLED.

BACKGROUND OF THE INVENTION

The latest OLED dominated a focus of developing flat panel display (FPD) technology in recent years. Compared with other FPDs such as LCDs (liquid crystal displays) and FEDs (Field emission displays), OLED display panels have many distinguished advantages such as light weight, high contrast, fast response speed, low power consumption and high brightness. However, there are many technical problems in the mass production and commercialization of OLED urgently needed to be solved.

For example, in the fabrication of OLED, the alignment of electrodes and prevention of short circuits between electrodes is still very important to the patterning and pixel quality of OLED. So far, the shadow mask process is widely applied in the fabrication of OLED to resolve such alignment problems of electrodes on the display panel of OLED. However, because multiple layers of different organic materials and cathode materials have to be deposited, it is difficult to use external shadow masks to accurately align each layer to form patterns on the substrate of panels, especially for the alignment of patterns with high resolution of multiple layers.

On the other hand, OLED with good display quality such as lifetime and reliability, simple processing method, low price, higher resolution, and thinner display panel (i.e. less thickness) is immediately necessary now. Nevertheless, because there are many technical problems still require to be overcome, the resolution and the thickness of OLED still cannot be effectively improved at the same time. Recently, several technologies are proposed to improve the processing of OLED, but obvious improvement on resolution and thickness of OLEDs is still very rare.

For example, Burrowa et al. disclosed a technology to form a multiple intrinsic shadow mask layer having an undercut on the substrate of display panel to accurately align the organic functional mediums and electrodes (e.g. anodes) in U.S. Pat. No. 6,013,538. The intrinsic shadow mask layer proposed by Burrowa et al. is made by multiple materials and complicated process. The cost of materials is high for this multiple shadow mask because many different materials are needed. The yield of this multiple shadow mask process is limited because complicate processing steps are required, too. In U.S. Pat. No. 5,962,970 Yokoi et al. disclosed another method to fabricate panels of organic light emitting devices. Yokoi et al. revealed in U.S. Pat. No. 5,962,970 a method to form a pattern of isolating layer having reverse-trapezoid cross-section to work as an intrinsic shadow mask and a wall to separate cathode materials from anodes for improving the display quality of the panels. However, the thickness (height) and the resolution of the isolating layer having reverse-trapezoid cross-section are limited. The thickness (or height) of isolating layer is required to be high enough (e.g. at least more than 6 μm) to avoid possible short circuits resulted from direct contact of cathode materials and anodes. As cathode formed through deposition, cathode materials will deposit on the protruding part of isolating layer. To

avoid direct contact between anode and cathode materials deposited on the side walls of insulating layers (owing to lateral diffusion of cathode materials in evaporative directions), the isolating layer having reverse-trapezoid cross-section should be wide enough to act as shadow walls to separate anode materials from cathode to avoid possible shorts. If the height of isolating layer is too low, the protruding part of the isolating layer will be not wide enough to separate the side-deposited cathode materials from contacting anodes. Thus, the thickness and the width of the isolating layer having reverse-trapezoid cross section cannot be effectively reduced. Therefore the corresponding resolution and the thickness of the panel of the OLED is limited. On the other hand, since the shape of the isolating layer is reverse-trapezoid, the width of the base of the isolating layer is narrower than the width of top. The width of the base of the isolating layer having reverse-trapezoid cross section are required to be wide enough to support the isolating layer and exempt from collapsing of isolating layer. The average minimum width of the isolating layer processed by the method taught in U.S. Pat. No. 5,962,970 is around 15 μm . The average minimum height of the isolating layer processed by the method described in U.S. Pat. No. 5,962,970 is around 6 μm . The corresponding resolution and the thickness of the panel of the OLED is significantly limited.

In 1997, another method for manufacturing organic emitting devices is disclosed in U.S. Pat. No. 5,701,055. Nagayama et al. disclosed a technology to form isolating layers on panel substrate to avoid direct contact between cathode materials and anodes in U.S. Pat. No. 5,701,055. In U.S. Pat. No. 5,701,055, isolating layers having multi-layer T-shaped cross-section or reverse-trapezoid cross-section is formed on the substrate to avoid direct contact between cathode materials and anodes. Thus the isolation between anodes and cathodes of organic light emitting devices can be solved. Nevertheless, the isolating layers having T-shaped cross-section multilayer disclosed in U.S. Pat. No. 5,701,055 are made by more than two materials. Multiple masks and lithographic processes are required for the formation of isolating layers having T-shaped cross-section in U.S. Pat. No. 5,701,055. The method for forming isolating layers having T-shaped cross-section in U.S. Pat. No. 5,701,055 solved the isolation between anodes and cathodes of OLED. However, the complicate steps of the method for forming isolating layers having T-shaped cross-section in U.S. Pat. No. 5,701,055 cost expensive because many different materials, reagents and complex processes are required. So far, the OLEDs meeting all the requirements such as relatively simple fabricating process, low cost, less material consumption, capability of mass production, high reproducible yield, high resolution and relatively low thickness are not disclosed yet and still in urgently demand now.

SUMMARY OF THE INVENTION

The object of the present invention is to provide a surface treatment process for fabricating a panel of an OLED having relatively high resolution and relatively low thickness.

Another object of the present invention is to provide a surface treatment process for preventing possible shorts of a panel of an OLED.

Another object of the present invention is to provide a surface treatment process of a panel of an OLED for facilitating the process, reducing cost and increasing the yield.

Another object of the present invention is to provide a surface treatment process for preventing OLEDs from shorts caused by lateral diffusion and collapse of the surface layers of OLEDs.

The surface treatment process for fabricating a panel of an OLED of the present invention comprising following steps: forming on a substrate a plurality of first electrodes; forming a plurality of ramparts having T-shape cross-section on said substrate and selectively on said first electrodes through coating positive chemically amplified photoresist compositions having photo-acid generators on said substrate, exposing coated substrate to ultraviolet (UV) radiation to form latent patterns, post-exposure surface-treating said photoresist on said substrate in an alkaline atmosphere and developing said photoresist; wherein each rampart protruding from said substrate and having an overhanging portion projecting in a direction parallel to said substrate; depositing organic electroluminescent media to the exposed areas between said ramparts on said substrate; forming a plurality of second electrodes on said organic electroluminescent media on said substrate.

The OLEDs of the present invention comprise: a substrate on which a plurality of first electrodes are formed; a plurality of ramparts having T-shape cross-section formed on said substrate and selectively on said first electrodes through coating positive chemically amplified photoresist compositions having photo-acid generators on said substrate, exposing coated substrate to UV radiation to form latent patterns, post-exposure surface-treating said photoresist on said substrate in an alkaline atmosphere and developing said photoresist; wherein each ramparts protruding from said substrate and having an overhanging portion projecting in a direction to said substrate; an organic function layers which includes at least one organic electroluminescent medium formed on the exposed areas between ramparts; and a plurality of second electrodes formed on organic functional layer.

BRIEF DESCRIPTION OF THE DRAWING

FIG. 1 is a partially enlarged perspective view of the panel of the present invention before formation of organic electroluminescent medium and second electrodes.

FIG. 2 is the cross-section view showing the panel achieved by the surface treatment process of the present invention.

FIG. 3 is a picture of top view of partial OLED panel made by the process illuminated in example 2.

DESCRIPTION OF THE PREFERRED EMBODIMENT

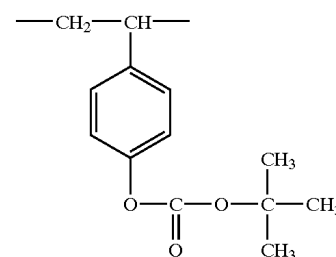
The surface treatment process of the present invention for fabricating a panel of an OLED having a plurality of emitting portions includes forming a plurality of first electrodes on a substrate at first. Then a plurality of ramparts having T-shape cross-section is formed on the substrate and selectively on the first electrodes. Such ramparts formed on the substrate and first electrodes are made through coating positive chemically amplified photoresist compositions having photo-acid generators on the substrate, exposing coated substrate to UV radiation to form latent patterns, post-exposure surface-treating said photoresist on said substrate in an alkaline atmosphere and developing said photoresist. The ramparts on the substrate protrudes from the substrate and having an overhanging portion projecting in a direction parallel to the substrate. Subsequently, organic electroluminescent media is formed to the exposed area between ramparts on the substrate. Furthermore, a plurality of second electrodes is formed on the organic electroluminescent media on the substrate to form a panel of an OLED.

The formation of first electrodes can be formed in patterns on substrate through conventional photolithography. There

is no limit for the patterns of first electrodes. However, patterns of stripes in parallel of first electrodes are preferred. The materials of first electrodes can be any conductive materials. Preferably, the first electrodes are transparent conductive materials such as InTiO_3 , InSnO_3 (ITO), SnO_2 , CdSnO , In_2O_3 doped with ZnO or antimony. The surface treatment process of the present invention can also selectively contains step of forming a plurality of auxiliary electrodes on the substrate through photolithography before forming first electrodes on the substrate. The formation of auxiliary electrodes is to increase the conductivity of first electrodes. The auxiliary electrodes are formed by processing substrates which are deposited by conductive materials before photolithography. The materials of auxiliary electrodes can be any conductive materials. Preferably, the auxiliary electrodes are made by chromium, aluminium, copper or silver. The patterns of auxiliary electrodes made through photolithography can be any form of patterns. Preferably, the auxiliary electrodes are parallel to first electrodes formed subsequently.

A pixel-defining layer can be selectively formed after first electrodes are formed. The pixel-defining layer can be formed in patterns through photolithography. The pixel-defining layer functions as an additional protective layer to isolate anodes and cathodes. The patterns of pixel-defining layer are not limited. However, patterns of pixel-defining layer with open portions above first electrodes are preferred. The pixel-defining layer can be any electrically insulated materials. Preferably, the pixel-defining layer is polyimide.

The ramparts on the panel of the OLEDs are made of positive chemically amplified photoresist compositions that contain photo-acid generators. The positive chemically amplified photoresist compositions also contain at least a polymer in addition to photo-acid generators. Preferably, the polymers used in the chemically amplified photoresist compositions are polymers having pendant tert-butoxyl carbonyl (t-BOC) protective groups connected to the backbone of the polymers. Most preferably, polymers of the positive chemically amplified photoresist compositions are polymers with following structures:



The positive chemically amplified photoresist compositions can further selectively contain other additives such as acid quenchers or solvents to improve the characteristics of the photoresist compositions or the ramparts. Any UV radiation that can initiate the photo-reaction of photoacid generators of the positive chemically amplified photoresist compositions can be adequate radiation sources for the process of the present invention. Preferably, the wavelength of adequate radiation source is about 254 nm. The positive chemically amplified photoresist compositions are used to form a plurality of ramparts having T-shape cross-section on the substrate. The ramparts having T-shape cross-section are formed by utilizing the interaction of the photo-acid generators and the UV radiation. The mechanism of forming ramparts having T-shape cross-section is accepted as fol-

lowing: As positive chemically amplified photoresist compositions exposed to radiation with adequate wavelength (e.g. wavelength about 254 nm), the photo-acid generators are initiated to release photo-acid anions. The released photo-acid anions are activated by following post-exposure surface-treating step. The activated photo-acid anions then react (e.g. deprotection) with the polymers in the positive chemically amplified photoresist compositions. The reaction is also catalyzed by photo-acid anions themselves to accelerate the reaction rates. As post-exposure surface treatment by alkaline atmosphere, the reaction catalyzed and initiated by photo-acid anions will be neutralized or quenched in the part near close to the surface of the area exposed to UV radiation. The region of quench or neutralization is only located on the surface of photoresist. Therefore, after post-exposure surface-treated in the alkaline atmosphere, the unexposed area of the positive chemically amplified photoresist compositions will form latent protruding ramparts having T-shape cross-section on substrates. The ramparts formed on the substrate by post-exposure surface-treating the positive chemically amplified photoresist compositions in alkaline atmosphere and developing the radiation-exposed positive chemically amplified photoresist compositions. The ramparts having T-shape cross-section is a serious drawback to be improved in the IC fabrication of semiconductor, though. Now, the ramparts having T-shape cross-section formed on the substrate of panels of OLEDs act as ideal shadow masks for subsequent deposition processes and serves as isolating walls to separate side-deposited cathode materials from anodes. The overhanging-parts of the T-shape cross-section can provide enough area and length for subsequent deposition of cathode materials and further prevent direct contact of cathode materials and anodes. The side-deposition of cathode materials is owing to the lateral diffusion of cathode materials as cathode materials evaporated. Hence, the reduction of photoresist thickness in this invention is significantly beneficial to decrease the possibility of lateral diffusion during cathode evaporation and meet the reliable yield and thin tendency of OLED panels. The alkaline atmosphere can be any atmosphere of alkaline solution. Preferably, the alkaline atmosphere is the atmosphere or vapors of tetramethyl ammonium hydroxide (TMAH) or potassium hydroxide that come from tetramethyl ammonium hydroxide or potassium hydroxide solution. The patterns of the ramparts can be patterns having open portions above first electrodes. Patterns in parallel strides and intersecting the first electrodes are preferable.

Organic electroluminescent media are formed after a plurality of first electrodes and ramparts are formed. The organic electroluminescent media are deposited on the substrate and selectively on first electrodes. The organic electroluminescent media are deposited as a single layer or optionally multiple layers (e.g. HTL, EL, ETL) on the substrate and selectively on first electrodes.

A plurality of second electrodes is then formed on the organic electroluminescent media on the substrate. The formation of second electrodes can be formed through conventional deposition methods. The organic electroluminescent media is sandwiched by second electrodes and first electrodes on the substrate. The open portions where first electrodes and second electrodes between ramparts are the emitting portions (i.e. pixels) of OLED. The second electrodes can be any electrically conductive materials. Preferably, the second electrodes are MgAg, aluminium, diamond, diamondlike or calcium.

The substrate that applied in the process of the present invention can be transparent or not transparent. Preferably,

the substrates used in the present invention are sodalime glasses, boron silica glasses, plastics or silicon wafers.

The ramparts formed through the surface treatment process of the present invention have relative stable bases (column base) than other ramparts formed through known other methods. The angles between the substrate and the column base of ramparts of the present invention are close to 90°. The nearly vertical base of ramparts support the ramparts solidly and prevent ramparts from collapsing. Compared with ramparts having reverse-trapezoid cross-section, the ramparts having T-shape cross-section are relatively strong and not apt to collapse. Even the width of the base of the ramparts is less than 1 μm (e.g. 0.18 μm), the ramparts having T-shape cross-section stand very well without collapsing. The height of the ramparts of the present invention doesn't need to be high. Even the height of the ramparts having T-shape cross-section is less than 6 μm (e.g. 4 μm), the ramparts having T-shape cross-section stand very well without collapsing. Therefore, the resolution of the OLEDs can be upgraded and the thickness the OLEDs can be reduced at the same time through the surface treatment process of the present invention. Besides, the ramparts of the present invention can reduce the deposition of second electrodes caused by lateral diffusion. The relative long overhanging part of the ramparts having T-shape cross-section provides enough wide or long area for isolating the side-deposition of second electrode material. Therefore, the possibility of short circuits resulted from direct contact of the first electrodes and the second electrode materials can be effectively reduced. On the other hand, the ramparts of the present invention are made by single material with single photolithography, the cost and complexity of photolithographic process decrease significantly.

FIG. 1 is a partially enlarged perspective view of the panel of the present invention before formation of organic electroluminescent medium and second electrodes. A plurality of auxiliary electrodes 70 is formed on the substrate 10 in parallel strides. Then a plurality of first electrodes 20 is formed in parallel stripes on the substrate 10. The first electrodes 20 are almost in the same height and each first electrode cover two auxiliary electrodes 70. A pixel-defining layer 60 in a pattern of multiple pixel windows is formed on the substrate 10 and first electrodes 20 subsequently. The open windows of the pixel-defining layer 60 locate above part of the first electrodes 20. Each stride of first electrodes 20 is separated into several open areas by the pixel-defining layer 60. A plurality of ramparts 50 which protrudes on the substrate 10 and have T-shape cross-section is formed on the pixel-defining layer 60 and the substrate 10. The ramparts 50 have an overhanging portion projecting in a direction parallel to the substrate 10. The ramparts 50 are in a pattern of parallel strides and cross over the first electrodes 20 perpendicularly. The open portions between ramparts 50 are above the open window areas of pixel-defining layer 60. The open window areas of pixel-defining layer 60 are the locations of future pixels after subsequent organic electroluminescent media 30 and second electrodes 40 form.

FIG. 2 is the cross-section view showing the panel achieved by the surface treatment process of the present invention. The auxiliary electrodes 70, first electrodes 20, pixel-defining layer 60 are formed as illustrated above. The organic electroluminescent media 30 is formed through deposition on the first electrodes 20 between ramparts 50. The second electrodes 40 are formed on the organic electroluminescent media 30 subsequently.

The organic light emitting device formed by the surface treatment process comprises a substrate on which a plurality

of first electrodes are formed; a plurality of ramparts in T-top shape cross-section formed on said substrate and selectively on said first electrodes through coating positive chemically amplified photoresist compositions having photo-acid generators on said substrate, exposing coated substrate to UV radiation to form pattern, post-exposure surface-treating said photoresist on said substrate in an alkaline atmosphere and developing said photoresist; wherein each ramparts protruding from said substrate and having an overhanging portion projecting in a direction to said substrate; an organic function layers which includes at least one organic electroluminescent medium formed on the exposed areas between ramparts; and a plurality of second electrodes formed on organic functional layer.

The OLEDs achieved through the surface treatment process of the present invention can be applied to any display of images, graphs, symbols, letters and characters for any apparatus. Preferably, the OLEDs of the present invention are applied to the display of televisions, computers, printers, screens, vehicles, signal machines, communication devices, telephones, lights, electric books, microdisplays, fishing machines, personal digital assistants (PDA), game machines, game goggles and airplanes.

More detailed examples are used to illustrate the present invention, and these examples are used to explain the present invention. The examples below, which are given simply by way of illustration, must not be taken to limit the scope of the invention.

EXAMPLE 1

A panel of an OLED was fabricated through the surface treatment process of the present invention.

ITO anodes were formed in a pattern of stripes on a cleaned glass substrate. Then a positive chemically amplified photoresist (APEX resist from Shipley corp.) composition was spin-coated on the substrate. The coated substrate was prebaked in ovens. A mask with a pattern in stripes was applied as the coated photoresist was exposed to radiation (deep UV). The exposed substrate was post-exposure baked and surface-treated with TMAH atmosphere at the same time. Ramparts of photoresist are formed in a parallel-stripe pattern. The stripes of ramparts formed are also perpendicular to the stripes of ITO. The ramparts formed on the substrate have T-shape cross-section. The width of ramparts stripes is about $0.18\ \mu\text{m}$ and the height of ramparts is about $0.8\ \mu\text{m}$. Then the exposed portions between ramparts are deposited by TPD (N,N'-diphenyl-N,N'-bis(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine) at a $700\ \text{\AA}$ thickness. Subsequently, Alq_3 is deposited on the same area at a $500\ \text{\AA}$ thickness. MgAg was deposited on the same area at a $1000\ \text{\AA}$ thickness to form a panel of an OLED.

EXAMPLE 2

A glass substrate which was coated with a layer of chromium and ITO was used as the substrate. The auxiliary electrodes were formed through photolithography in a pattern of parallel stripes. Then ITO electrodes are formed in a pattern of parallel stripes as described in example 1. Then a polyimide was coated on the substrate and form a pattern through photolithography and curing at a temperature of 300°C . Then the ramparts were formed as described in example 1. The substrate with polyimide pixel-defining layer, first electrodes and auxiliary electrodes was shown in FIGS. 1 and 2. Subsequent deposition of organic electroluminescent layer and MgAg was achieved as described in

example 1. Then a panel of an OLED was achieved through the surface treatment process of the present invention.

From the foregoing description, one skilled in the art can easily ascertain the essential characteristics of this invention, and, without departing from the scope thereof, can make various changes and modifications of the invention to adapt it to various usages and conditions. Thus, other embodiments are also within the claims.

What is claimed is:

1. An organic light emitting device having a plurality of emitting portions comprising:

a substrate on which a plurality of first electrodes are formed;

a plurality of ramparts having T-shape cross-section formed on said substrate and selectively on said first electrodes through coating positive chemically amplified photoresist compositions having photo-acid generators on said substrate, exposing coated substrate to UV radiation to form latent pattern, post-exposure surface-treating said photoresist on said substrate in an alkaline atmosphere and developing said photoresist; wherein each ramparts protruding from said substrate and having an overhanging portion projecting in a direction to said substrate;

an organic function layers which includes at least one organic electroluminescent medium formed on the exposed areas between ramparts; and

a plurality of second electrodes formed on organic functional layers.

2. The device of claim 1 further comprising a plurality of auxiliary electrodes on said substrate.

3. The device of claim 1, wherein said ramparts perpendicularly cross said first electrodes.

4. The device of claim 1 further comprising a pixel-defining polyimide layer selectively on substrate and first electrodes.

5. The device of claim 1, wherein the thickness of said ramparts is less than $6\ \mu\text{m}$.

6. The device of claim 1, wherein said ramparts are entirely made of a single material.

7. An organic light emitting device, comprising:

a substrate,

a plurality of first electrodes formed on top of said substrate;

a plurality of ramparts made of a single material and formed on top of said substrate and said first electrodes, each of said ramparts having a generally T-shaped cross section including an upright portion and an overhanging portion positioned on top of said upright portion;

a plurality of organic electroluminescent layers formed in regions between adjacent said ramparts; and

a plurality of second electrodes formed on of said organic electroluminescent layers.

8. The device of claim 7, further comprising a plurality of third electrodes formed on top of said substrate, each of said third electrodes physically and electrically contacting one of said first electrodes.

9. The device of claim 7, wherein said first electrodes are formed as stripes extending in a first direction, said ramparts are formed as stripes extending in a second direction substantially perpendicular to said first direction, and said overhanging portions of said ramparts are substantially parallel to said substrate.

10. The device of claim 7, further comprising a pixel-defining layer formed on top of said substrate and said first electrode.

9

11. The device of claim 7, wherein a height of said ramparts is less than 6 μm .

12. The device of claim 8, wherein said first and third electrodes are substantially parallel.

13. The device of claim 10, wherein said pixel-defining layer is made of polyimide. 5

14. The device of claim 10, wherein said pixel-defining layer has a plurality of windows through which predetermined areas of said first electrodes are exposed.

15. The device of claim 14, wherein said pixel-defining layer comprises a plurality of first stripes extending substantially parallel to said first electrodes and a plurality of second stripes extending substantially parallel to said ramparts, said first and second stripes crossing each other to define said windows. 10

10

16. The device of claim 15, wherein the upright portions of said ramparts extend upwardly from said second stripes of said pixel-defining layer.

17. The device of claim 15, wherein said first stripes are in direct physical contact with said substrate.

18. The device of claim 7, wherein said single material is a developed photoresist composition.

19. The device of claim 7, wherein said single material is formed by coating a positive chemically amplified photoresist composition having photo-acid generators on said substrate, exposing the coated substrate to UV radiation to form a latent pattern, post-exposure surface treating said photoresist in an alkaline atmosphere, and developing said photoresist.

* * * * *

专利名称(译)	用于制造有机发光器件的面板的表面处理工艺		
公开(公告)号	US6630785	公开(公告)日	2003-10-07
申请号	US09/580487	申请日	2000-05-30
[标]申请(专利权)人(译)	铼宝科技股份有限公司		
申请(专利权)人(译)	铼宝科技股份有限公司		
当前申请(专利权)人(译)	RITEK显示科技有限公司.		
[标]发明人	LU TIEN RONG		
发明人	LU, TIEN-RONG		
IPC分类号	H01L27/28 H01L27/32 H05B33/00		
CPC分类号	H01L27/3283		
审查员(译)	帕特尔贵宾		
助理审查员(译)	WILLIAMS , JOSEPH		
外部链接	Espacenet USPTO		

摘要(译)

公开了一种用于制造有机发光器件的面板的表面处理工艺。用于制造有机发光器件的面板的表面处理工艺包括以下步骤：在基板上形成多个第一电极；通过在所述基板上涂覆具有光酸产生剂的正性化学放大光致抗蚀剂组合物，在所述基板上形成多个具有T形横截面的壁，并选择性地地在所述第一电极上，将涂覆的基板暴露于UV辐射以形成潜在图案，曝光表面在碱性气氛中处理所述基板上的所述光刻胶并显影所述光刻胶；其中每个壁垒从所述基板突出并具有在平行于所述基板的方向上突出的悬垂部分；将有机电致发光介质沉积到所述基板上的所述壁垒之间的暴露区域；在所述衬底上的所述有机电致发光介质上形成多个第二电极。

